

# Diode Pumped Sub-Nanosecond Passively Q-Switched Laser

## MPL1310

### FEATURES

- > Up to **1 mJ** pulse energy at **1064 nm**
- > Short pulse duration **< 350 ps**
- > Variable up to **100 Hz** repetition rate
- > Ultra-compact
- > Passively Q-switched
- > Average power **100 mW**
- > High peak power **2.8 MW**
- > Guaranteed **> 3 Gshot** lifetime
- > Other wavelengths (e.g. 1053 nm, 1342 nm, 671 nm, 447 nm) are available

### APPLICATIONS

- > Laser-Induced Breakdown Spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- > Ignition of gas mixtures

**MPL1310** series DPSS passively Q-switched sub-nanosecond lasers deliver high peak powers at 100 Hz repetition rate. Short laser cavity is fixed on thermo-stabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Sub-nanosecond pulse duration of < 350 ps, high pulse energy more than 1 mJ and variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others. Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 2.8 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.



# Specifications <sup>1)</sup>

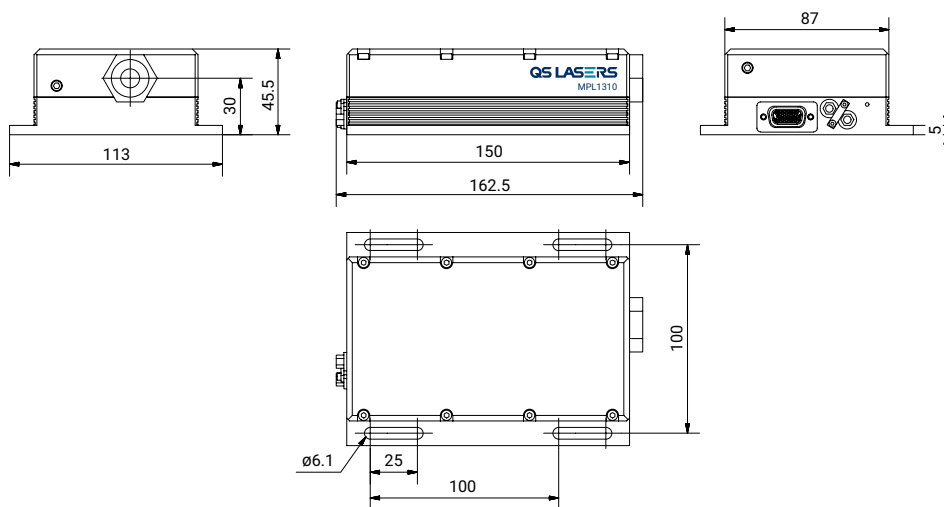
MODEL	MPL1310	MPL1310-MO
<b>Pulse energy</b>		
at 1064 nm	1 mJ	0.2 mJ
at 532 nm	0.5 mJ	0.1 mJ
at 355 nm	0.25 mJ	0.05 mJ
at 266 nm	0.15 mJ	–
<b>Typical pulse duration</b>	< 350 ps <sup>2)</sup>	< 250 ps <sup>2)</sup>
<b>Pulse to pulse energy stability (RMS)</b>		
at 1064 nm	< 1 % <sup>3)</sup>	
at 532 nm	< 2.5 % <sup>3)</sup>	
at 355 nm	< 3.5 % <sup>3)</sup>	
at 266 nm	< 5.0 % <sup>3)</sup>	
<b>Power drift</b>	± 3.0 % <sup>4)</sup>	
<b>Pulse repetition rate <sup>5)</sup></b>	1 – 100 Hz	
<b>Beam profile</b>	Close to Gaussian	
<b>Beam divergence <sup>6)</sup></b>	< 6 mrad	
<b>Polarization</b>	Linear, horizontal at 1064 nm	
<b>Spectral linewidth</b>	SLM	
<b>Beam pointing stability <sup>7)</sup></b>	< 40 μrad	
<b>Typical beam diameter <sup>8)</sup></b>	1.5 mm	1 mm
<b>Jitter</b>	~ 2 μs RMS <sup>9)</sup>	

## DIMENSIONS

Laser head (W×L×H)	113 × 162.5 × 45.5 mm
Controller unit (W×L×H)	75 × 200 × 70 mm (OEM version)
Power adapter (W×L×H)	119 × 179 × 30 mm (OEM version)

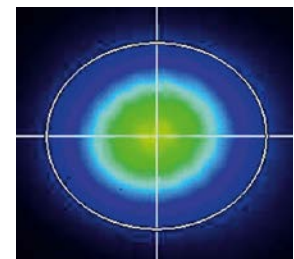
## OPERATING REQUIREMENTS

Cooling requirements	Air cooled
Ambient temperature	15 – 30 °C
Relative humidity (non-condensing)	10 – 80 %
Mains voltage	90 – 230 VAC, single phase, 47 – 63 Hz <sup>10)</sup>
Power consumption	< 20 W



MPL1310 laser head dimensions (in mm)

- <sup>1)</sup> Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- <sup>2)</sup> FWHM level at 1064 nm. Other pulse duration is available by request. Please inquire for detailed specifications.
- <sup>3)</sup> Averaged from 60 seconds time interval in 5 series.
- <sup>4)</sup> Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- <sup>5)</sup> Factory-set pulse repetition rate is fixed at 100 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- <sup>6)</sup> Full angle measured at the 1/e<sup>2</sup> level.
- <sup>7)</sup> RMS value measured from 1000 shots.
- <sup>8)</sup> Beam diameter is measured 20 cm from laser output at the 1/e<sup>2</sup> level.
- <sup>9)</sup> In respect to Q-switch triggering rising edge pulse.
- <sup>10)</sup> Laser can be powered from appropriate 12 VDC power source. Inquire for details.



Typical beam intensity profile (20 cm from laser output) of MPL1310 series lasers